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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	864
Number of Logic Elements/Cells	3888
Total RAM Bits	49152
Number of I/O	176
Number of Gates	150000
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	256-BGA
Supplier Device Package	256-FBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xc2s150-5fgg256i

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



Figure 4: Spartan-II CLB Slice (two identical slices in each CLB)

Storage Elements

Storage elements in the Spartan-II FPGA slice can be configured either as edge-triggered D-type flip-flops or as level-sensitive latches. The D inputs can be driven either by function generators within the slice or directly from slice inputs, bypassing the function generators.

In addition to Clock and Clock Enable signals, each slice has synchronous set and reset signals (SR and BY). SR forces a storage element into the initialization state specified for it in the configuration. BY forces it into the opposite state. Alternatively, these signals may be configured to operate asynchronously.

All control signals are independently invertible, and are shared by the two flip-flops within the slice.

Additional Logic

The F5 multiplexer in each slice combines the function generator outputs. This combination provides either a function generator that can implement any 5-input function, a 4:1 multiplexer, or selected functions of up to nine inputs.



Figure 7: BUFT Connections to Dedicated Horizontal Bus Lines

Clock Distribution

The Spartan-II family provides high-speed, low-skew clock distribution through the primary global routing resources described above. A typical clock distribution net is shown in Figure 8.

Four global buffers are provided, two at the top center of the device and two at the bottom center. These drive the four primary global nets that in turn drive any clock pin.

Four dedicated clock pads are provided, one adjacent to each of the global buffers. The input to the global buffer is selected either from these pads or from signals in the general purpose routing. Global clock pins do not have the option for internal, weak pull-up resistors.



Figure 8: Global Clock Distribution Network

Delay-Locked Loop (DLL)

Associated with each global clock input buffer is a fully digital Delay-Locked Loop (DLL) that can eliminate skew between the clock input pad and internal clock-input pins throughout the device. Each DLL can drive two global clock networks. The DLL monitors the input clock and the distributed clock, and automatically adjusts a clock delay element. Additional delay is introduced such that clock edges reach internal flip-flops exactly one clock period after they arrive at the input. This closed-loop system effectively eliminates clock-distribution delay by ensuring that clock edges arrive at internal flip-flops in synchronism with clock edges arriving at the input.

In addition to eliminating clock-distribution delay, the DLL provides advanced control of multiple clock domains. The DLL provides four quadrature phases of the source clock, can double the clock, or divide the clock by 1.5, 2, 2.5, 3, 4, 5, 8, or 16. It has six outputs.

The DLL also operates as a clock mirror. By driving the output from a DLL off-chip and then back on again, the DLL can be used to deskew a board level clock among multiple Spartan-II devices.

In order to guarantee that the system clock is operating correctly prior to the FPGA starting up after configuration, the DLL can delay the completion of the configuration process until after it has achieved lock.

Boundary Scan

Spartan-II devices support all the mandatory boundaryscan instructions specified in the IEEE standard 1149.1. A Test Access Port (TAP) and registers are provided that implement the EXTEST, SAMPLE/PRELOAD, and BYPASS instructions. The TAP also supports two USERCODE instructions and internal scan chains.

The TAP uses dedicated package pins that always operate using LVTTL. For TDO to operate using LVTTL, the V_{CCO} for Bank 2 must be 3.3V. Otherwise, TDO switches rail-to-rail between ground and V_{CCO}. TDI, TMS, and TCK have a default internal weak pull-up resistor, and TDO has no default resistor. Bitstream options allow setting any of the four TAP pins to have an internal pull-up, pull-down, or neither.

By default, these operations are synchronized to CCLK. The entire start-up sequence lasts eight cycles, called C0-C7, after which the loaded design is fully functional. The default timing for start-up is shown in the top half of Figure 13. The four operations can be selected to switch on any CCLK cycle C1-C6 through settings in the Xilinx software. Heavy lines show default settings.



Figure 13: Start-Up Waveforms

The bottom half of Figure 13 shows another commonly used version of the start-up timing known as Sync-to-DONE. This version makes the GTS, GSR, and GWE events conditional upon the DONE pin going High. This timing is important for a daisy chain of multiple FPGAs in serial mode, since it ensures that all FPGAs go through start-up together, after all their DONE pins have gone High.

Sync-to-DONE timing is selected by setting the GTS, GSR, and GWE cycles to a value of DONE in the configuration options. This causes these signals to transition one clock cycle after DONE externally transitions High.

Serial Modes

There are two serial configuration modes: In Master Serial mode, the FPGA controls the configuration process by driving CCLK as an output. In Slave Serial mode, the FPGA passively receives CCLK as an input from an external agent (e.g., a microprocessor, CPLD, or second FPGA in master mode) that is controlling the configuration process. In both modes, the FPGA is configured by loading one bit per CCLK cycle. The MSB of each configuration data byte is always written to the DIN pin first.

See Figure 14 for the sequence for loading data into the Spartan-II FPGA serially. This is an expansion of the "Load Configuration Data Frames" block in Figure 11. Note that CS and WRITE normally are not used during serial configuration. To ensure successful loading of the FPGA, do not toggle WRITE with CS Low during serial configuration.





If CCLK is slower than $\rm F_{CCNH},$ the FPGA will never assert BUSY. In this case, the above handshake is unnecessary, and data can simply be entered into the FPGA every CCLK cycle.



Figure 19: Loading Configuration Data for the Slave Parallel Mode

A configuration packet does not have to be written in one continuous stretch, rather it can be split into many write sequences. Each sequence would involve assertion of \overline{CS} .

In applications where multiple clock cycles may be required to access the configuration data before each byte can be loaded into the Slave Parallel interface, a new byte of data may not be ready for each consecutive CCLK edge. In such a case the \overline{CS} signal may be de-asserted until the next byte is valid on D0-D7. While \overline{CS} is High, the Slave Parallel interface does not expect any data and ignores all CCLK transitions. However, to avoid aborting configuration, WRITE must continue to be asserted while CS is asserted.

Abort

To abort configuration during a write sequence, de-assert $\overline{\text{WRITE}}$ while holding $\overline{\text{CS}}$ Low. The abort operation is initiated at the rising edge of CCLK, as shown in Figure 21, page 26. The device will remain BUSY until the aborted operation is complete. After aborting configuration, data is assumed to be unaligned to word boundaries and the FPGA requires a new synchronization word prior to accepting any new packets.

Boundary-Scan Mode

In the boundary-scan mode, no nondedicated pins are required, configuration being done entirely through the IEEE 1149.1 Test Access Port.

Configuration through the TAP uses the special CFG_IN instruction. This instruction allows data input on TDI to be converted into data packets for the internal configuration bus.

The following steps are required to configure the FPGA through the boundary-scan port.

- 1. Load the CFG_IN instruction into the boundary-scan instruction register (IR)
- 2. Enter the Shift-DR (SDR) state
- 3. Shift a standard configuration bitstream into TDI
- 4. Return to Run-Test-Idle (RTI)
- 5. Load the JSTART instruction into IR
- 6. Enter the SDR state
- 7. Clock TCK through the sequence (the length is programmable)
- 8. Return to RTI

Configuration and readback via the TAP is always available. The boundary-scan mode simply locks out the other modes. The boundary-scan mode is selected by a <10x> on the mode pins (M0, M1, M2).

Readback

The configuration data stored in the Spartan-II FPGA configuration memory can be readback for verification. Along with the configuration data it is possible to readback the contents of all flip-flops/latches, LUT RAMs, and block RAMs. This capability is used for real-time debugging.

For more detailed information see <u>XAPP176</u>, Spartan-II FPGA Family Configuration and Readback.

Startup Delay Property

This property, STARTUP_WAIT, takes on a value of TRUE or FALSE (the default value). When TRUE the Startup Sequence following device configuration is paused at a user-specified point until the DLL locks. <u>XAPP176</u>: *Configuration and Readback of the Spartan-II and Spartan-IIE Families* explains how this can result in delaying the assertion of the DONE pin until the DLL locks.

DLL Location Constraints

The DLLs are distributed such that there is one DLL in each corner of the device. The location constraint LOC, attached to the DLL primitive with the numeric identifier 0, 1, 2, or 3, controls DLL location. The orientation of the four DLLs and their corresponding clock resources appears in Figure 27.

The LOC property uses the following form.

LOC = DLL2



Figure 27: Orientation of DLLs

Design Considerations

Use the following design considerations to avoid pitfalls and improve success designing with Xilinx devices.

Input Clock

The output clock signal of a DLL, essentially a delayed version of the input clock signal, reflects any instability on the input clock in the output waveform. For this reason the quality of the DLL input clock relates directly to the quality of the output clock waveforms generated by the DLL. The DLL input clock requirements are specified in the "DLL Timing Parameters" section of the data sheet.

In most systems a crystal oscillator generates the system clock. The DLL can be used with any commercially available quartz crystal oscillator. For example, most crystal oscillators produce an output waveform with a frequency tolerance of 100 PPM, meaning 0.01 percent change in the clock period. The DLL operates reliably on an input waveform with a frequency drift of up to 1 ns — orders of magnitude in excess of that needed to support any crystal oscillator in the industry. However, the cycle-to-cycle jitter must be kept to less than 300 ps in the low frequencies and 150 ps for the high frequencies.

Input Clock Changes

Changing the period of the input clock beyond the maximum drift amount requires a manual reset of the CLKDLL. Failure to reset the DLL will produce an unreliable lock signal and output clock.

It is possible to stop the input clock in a way that has little impact to the DLL. Stopping the clock should be limited to less than approximately 100 μ s to keep device cooling to a minimum and maintain the validity of the current tap setting. The clock should be stopped during a Low phase, and when restored the full High period should be seen. During this time LOCKED will stay High and remain High when the clock is restored. If these conditions may not be met in the design, apply a manual reset to the DLL after re-starting the input clock, even if the LOCKED signal has not changed.

When the clock is stopped, one to four more clocks will still be observed as the delay line is flushed. When the clock is restarted, the output clocks will not be observed for one to four clocks as the delay line is filled. The most common case will be two or three clocks.

In a similar manner, a phase shift of the input clock is also possible. The phase shift will propagate to the output one to four clocks after the original shift, with no disruption to the CLKDLL control.

Output Clocks

As mentioned earlier in the DLL pin descriptions, some restrictions apply regarding the connectivity of the output pins. The DLL clock outputs can drive an OBUF, a global clock buffer BUFG, or route directly to destination clock pins. The only BUFGs that the DLL clock outputs can drive are the two on the same edge of the device (top or bottom). One DLL output can drive more than one OBUF; however, this adds skew.

Do not use the DLL output clock signals until after activation of the LOCKED signal. Prior to the activation of the LOCKED signal, the DLL output clocks are not valid and can exhibit glitches, spikes, or other spurious movement.



Figure 33: Timing Diagram for Single-Port Block RAM Memory



Figure 34: Timing Diagram for a True Dual-Port Read/Write Block RAM Memory

At the third rising edge of CLKA, the T_{BCCS} parameter is violated with two writes to memory location 0x0F. The DOA and DOB busses reflect the contents of the DIA and DIB busses, but the stored value at 0x7E is invalid.

At the fourth rising edge of CLKA, a read operation is performed at memory location 0x0F and invalid data is present on the DOA bus. Port B also executes a read operation to memory location 0x0F and also reads invalid data.

At the fifth rising edge of CLKA a read operation is performed that does not violate the T_{BCCS} parameter to the previous write of 0x7E by Port B. THe DOA bus reflects the recently written value by Port B.

Initialization

The block RAM memory can initialize during the device configuration sequence. The 16 initialization properties of 64 hex values each (a total of 4096 bits) set the initialization of each RAM. These properties appear in Table 14. Any initialization properties not explicitly set configure as zeros. Partial initialization strings pad with zeros. Initialization strings greater than 64 hex values generate an error. The RAMs can be simulated with the initialization values using generics in VHDL simulators and parameters in Verilog simulators.

Initialization in VHDL

The block RAM structures may be initialized in VHDL for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the VHDL code uses a generic to pass the initialization.

Initialization in Verilog

The block RAM structures may be initialized in Verilog for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the Verilog code uses a defparam to pass the initialization.

Block Memory Generation

The CORE Generator[™] software generates memory structures using the block RAM features. This program outputs VHDL or Verilog simulation code templates and an EDIF file for inclusion in a design.

|--|

Property	Memory Cells
INIT_00	255 to 0
INIT_01	511 to 256
INIT_02	767 to 512
INIT_03	1023 to 768
INIT_04	1279 to 1024

	Table	14:	RAM	Initialization	Pro	perties
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Property	Memory Cells
INIT_05	1535 to 1280
INIT_06	1791 to 1536
INIT_07	2047 to 1792
INIT_08	2303 to 2048
INIT_09	2559 to 2304
INIT_0a	2815 to 2560
INIT_0b	3071 to 2816
INIT_0c	3327 to 3072
INIT_0d	3583 to 3328
INIT_0e	3839 to 3584
INIT_0f	4095 to 3840

For design examples and more information on using the Block RAM, see <u>XAPP173</u>, Using Block SelectRAM+ Memory in Spartan-II FPGAs.

Using Versatile I/O

The Spartan-II FPGA family includes a highly configurable, high-performance I/O resource called Versatile I/O to provide support for a wide variety of I/O standards. The Versatile I/O resource is a robust set of features including programmable control of output drive strength, slew rate, and input delay and hold time. Taking advantage of the flexibility and Versatile I/O features and the design considerations described in this document can improve and simplify system level design.

Introduction

As FPGAs continue to grow in size and capacity, the larger and more complex systems designed for them demand an increased variety of I/O standards. Furthermore, as system clock speeds continue to increase, the need for high-performance I/O becomes more important. While chip-to-chip delays have an increasingly substantial impact on overall system speed, the task of achieving the desired system performance becomes more difficult with the proliferation of low-voltage I/O standards. Versatile I/O, the revolutionary input/output resources of Spartan-II devices, has resolved this potential problem by providing a highly configurable, high-performance alternative to the I/O resources of more conventional programmable devices. The Spartan-II FPGA Versatile I/O features combine the flexibility and time-to-market advantages of programmable logic with the high performance previously available only with ASICs and custom ICs.

Each Versatile I/O block can support up to 16 I/O standards. Supporting such a variety of I/O standards allows the

IOBUF_<slew_rate>_<drive_strength>

<slew_rate> can be either F (Fast), or S (Slow) and <drive_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24).





When the IOBUF primitive supports an I/O standard such as LVTTL, LVCMOS, or PCI33_5, the IBUF automatically configures as a 5V tolerant input buffer unless the V_{CCO} for the bank is less than 2V. If the single-ended IBUF is placed in a bank with an HSTL standard (V_{CCO} < 2V), the input buffer is not 5V tolerant.

The voltage reference signal is "banked" within the Spartan-II device on a half-edge basis such that for all packages there are eight independent V_{REF} banks internally. See Figure 36, page 39 for a representation of the Spartan-II FPGA I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a V_{REF} input.

Additional restrictions on the Versatile I/O IOBUF placement require that within a given V_{CCO} bank each IOBUF must share the same output source drive voltage. Input buffers of any type and output buffers that do not require V_{CCO} can be placed within the same V_{CCO} bank. The LOC property can specify a location for the IOBUF.

An optional delay element is associated with the input path in each IOBUF. When the IOBUF drives an input flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Override this default with the NODELAY=TRUE property.

In the case when the IOBUF does not drive an input flip-flop within the IOB, the delay element de-activates by default to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

3-state output buffers and bidirectional buffers can have either a weak pull-up resistor, a weak pull-down resistor, or a weak "keeper" circuit. Control this feature by adding the appropriate primitive to the output net of the IOBUF (PULLUP, PULLDOWN, or KEEPER).

Versatile I/O Properties

Access to some of the Versatile I/O features (for example, location constraints, input delay, output drive strength, and slew rate) is available through properties associated with these features.

Input Delay Properties

An optional delay element is associated with each IBUF. When the IBUF drives a flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Use the NODELAY=TRUE property to override this default.

In the case when the IBUF does not drive a flip-flop within the IOB, the delay element by default de-activates to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

IOB Flip-Flop/Latch Property

The I/O Block (IOB) includes an optional register on the input path, an optional register on the output path, and an optional register on the 3-state control pin. The design implementation software automatically takes advantage of these registers when the following option for the Map program is specified:

map -pr b <filename>

Alternatively, the IOB = TRUE property can be placed on a register to force the mapper to place the register in an IOB.

Location Constraints

Specify the location of each Versatile I/O primitive with the location constraint LOC attached to the Versatile I/O primitive. The external port identifier indicates the value of the location constrain. The format of the port identifier depends on the package chosen for the specific design.

The LOC properties use the following form:

LOC=A42 LOC=P37

Output Slew Rate Property

In the case of the LVTTL output buffers (OBUF, OBUFT, and IOBUF), slew rate control can be programmed with the SLEW= property. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals. The SLEW= property has one of the two following values.

SLEW=SLOW

SLEW=FAST

Output Drive Strength Property

For the LVTTL output buffers (OBUF, OBUFT, and IOBUF, the desired drive strength can be specified with the DRIVE=

SSTL2_I

A sample circuit illustrating a valid termination technique for SSTL2_I appears in Figure 49. DC voltage specifications appear in Table 27 for the SSTL2_I standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics

SSTL2 Class I



Figure 49: Terminated SSTL2 Class I

Table 2	7: SSTL2_	Voltage	Specifications
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Parameter	Min	Тур	Max
V _{CCO}	2.3	2.5	2.7
$V_{REF} = 0.5 \times V_{CCO}$	1.15	1.25	1.35
$V_{TT} = V_{REF} + N^{(1)}$	1.11	1.25	1.39
$V_{IH} \ge V_{REF} + 0.18$	1.33	1.43	3.0 ⁽²⁾
$V_{IL} \leq V_{REF} - 0.18$	-0.3 ⁽³⁾	1.07	1.17
V _{OH} ≥ V _{REF} + 0.61	1.76	-	-
$V_{OL} \le V_{REF} - 0.61$	-	-	0.74
I _{OH} at V _{OH} (mA)	-7.6	-	-
I _{OL} at V _{OL} (mA)	7.6	-	-

Notes:

- 1. N must be greater than or equal to -0.04 and less than or equal to 0.04.
- 2. V_{IH} maximum is V_{CCO} + 0.3.
- 3. V_{IL} minimum does not conform to the formula.

SSTL2 Class II

A sample circuit illustrating a valid termination technique for SSTL2_II appears in Figure 50. DC voltage specifications appear in Table 28 for the SSTL2_II standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.



Figure 50: Terminated SSTL2 Class II

Table 28: SSTL2_II Voltage Specifications

Parameter	Min	Тур	Max
V _{CCO}	2.3	2.5	2.7
$V_{REF} = 0.5 \times V_{CCO}$	1.15	1.25	1.35
$V_{TT} = V_{REF} + N^{(1)}$	1.11	1.25	1.39
$V_{IH} \ge V_{REF} + 0.18$	1.33	1.43	3.0 ⁽²⁾
$V_{IL} \leq V_{REF} - 0.18$	-0.3 ⁽³⁾	1.07	1.17
$V_{OH} \ge V_{REF} + 0.8$	1.95	-	-
$V_{OL} \leq V_{REF} - 0.8$	-	-	0.55
I _{OH} at V _{OH} (mA)	-15.2	-	-
I _{OL} at V _{OL} (mA)	15.2	-	-

Notes:

- 1. N must be greater than or equal to -0.04 and less than or equal to 0.04.
- 2. V_{IH} maximum is V_{CCO} + 0.3.
- 3. V_{IL} minimum does not conform to the formula.

Revision History

Date	Version	Description
09/18/00	2.0	Sectioned the Spartan-II Family data sheet into four modules. Corrected banking description.
03/05/01	2.1	Clarified guidelines for applying power to $V_{\mbox{CCINT}}$ and $V_{\mbox{CCO}}$
09/03/03	2.2	 The following changes were made: "Serial Modes," page 20 cautions about toggling WRITE during serial configuration. Maximum V_{IH} values in Table 32 and Table 33 changed to 5.5V. In "Boundary Scan," page 13, removed sentence about lack of INTEST support. In Table 9, page 17, added note about the state of I/Os after power-on. In "Slave Parallel Mode," page 23, explained configuration bit alignment to SelectMap port.
06/13/08	2.8	Added note that TDI, TMS, and TCK have a default pull-up resistor. Added note on maximum daisy chain limit. Updated Figure 15 and Figure 18 since Mode pins can be pulled up to either 2.5V or 3.3V. Updated DLL section. Recommended using property or attribute instead of primitive to define I/O properties. Updated description and links. Updated all modules for continuous page, figure, and table numbering. Synchronized all modules to v2.8.

Clock Distribution Guidelines⁽¹⁾

	Speed	l Grade			
		-6	-5		
Symbol	Description	Max	Max	Units	
GCLK Clock Skew					
T _{GSKEWIOB}	Global clock skew between IOB flip-flops	0.13	0.14	ns	

Notes:

1. These clock distribution delays are provided for guidance only. They reflect the delays encountered in a typical design under worst-case conditions. Precise values for a particular design are provided by the timing analyzer.

Clock Distribution Switching Characteristics

T_{GPIO} is specified for LVTTL levels. For other standards, adjust T_{GPIO} with the values shown in "I/O Standard Global Clock Input Adjustments".

		Speed Grade		
		-6	-5	
Symbol	Description	Max	Max	Units
GCLK IOB and Buffer				
T _{GPIO}	Global clock pad to output	0.7	0.8	ns
T _{GIO}	Global clock buffer I input to O output	0.7	0.8	ns

I/O Standard Global Clock Input Adjustments

Delays associated with a global clock input pad are specified for LVTTL levels. For other standards, adjust the delays by the values shown. A delay adjusted in this way constitutes a worst-case limit.

			Speed	Grade	
Symbol	Description	Standard	-6	-5	Units
Data Input Delay A	djustments				
T _{GPLVTTL}	Standard-specific global clock	LVTTL	0	0	ns
T _{GPLVCMOS2}	input delay adjustments	LVCMOS2	-0.04	-0.05	ns
T _{GPPCI33_3}		PCI, 33 MHz, 3.3V	-0.11	-0.13	ns
T _{GPPCI33_5}		PCI, 33 MHz, 5.0V	0.26	0.30	ns
T _{GPPCI66_3}		PCI, 66 MHz, 3.3V	-0.11	-0.13	ns
T _{GPGTL}		GTL	0.80	0.84	ns
T _{GPGTLP}		GTL+	0.71	0.73	ns
T _{GPHSTL}		HSTL	0.63	0.64	ns
T _{GPSSTL2}		SSTL2	0.52	0.51	ns
T _{GPSSTL3}		SSTL3	0.56	0.55	ns
T _{GPCTT}		CTT	0.62	0.62	ns
T _{GPAGP}		AGP	0.54	0.53	ns

Notes:

1. Input timing for GPLVTTL is measured at 1.4V. For other I/O standards, see the table "Delay Measurement Methodology," page 60.

CLB Switching Characteristics

Delays originating at F/G inputs vary slightly according to the input used. The values listed below are worst-case. Precise values are provided by the timing analyzer.

			Speed Grade				
		-(6		5		
Symbol	Description	Min	Max	Min	Max	Units	
Combinatorial Dela	ays						
T _{ILO}	4-input function: F/G inputs to X/Y outputs	-	0.6	-	0.7	ns	
T _{IF5}	5-input function: F/G inputs to F5 output	-	0.7	-	0.9	ns	
T _{IF5X}	5-input function: F/G inputs to X output	-	0.9	-	1.1	ns	
T _{IF6Y}	6-input function: F/G inputs to Y output via F6 MUX	-	1.0	-	1.1	ns	
T _{F5INY}	6-input function: F5IN input to Y output	-	0.4	-	0.4	ns	
T _{IFNCTL}	Incremental delay routing through transparent latch to XQ/YQ outputs	-	0.7	-	0.9	ns	
T _{BYYB}	BY input to YB output	-	0.6	-	0.7	ns	
Sequential Delays	1			1			
Т _{СКО}	FF clock CLK to XQ/YQ outputs	-	1.1	-	1.3	ns	
T _{CKLO}	Latch clock CLK to XQ/YQ outputs	-	1.2	-	1.5	ns	
Setup/Hold Times	with Respect to Clock CLK ⁽¹⁾			1			
Т _{ІСК} / Т _{СКІ}	4-input function: F/G inputs	1.3/0	-	1.4 / 0		ns	
T _{IF5CK} / T _{CKIF5}	5-input function: F/G inputs	1.6/0	-	1.8/0	-	ns	
T _{F5INCK} / T _{CKF5IN}	6-input function: F5IN input	1.0/0	-	1.1/0	-	ns	
T _{IF6CK} / T _{CKIF6}	6-input function: F/G inputs via F6 MUX	1.6 / 0	-	1.8 / 0	-	ns	
T _{DICK} / T _{CKDI}	BX/BY inputs	0.8/0	-	0.8/0	-	ns	
T _{CECK} / T _{CKCE}	CE input	0.9/0	-	0.9/0	-	ns	
T _{RCK} / T _{CKR}	SR/BY inputs (synchronous)	0.8/0	-	0.8/0	-	ns	
Clock CLK	·	1					
Т _{СН}	Minimum pulse width, High	-	1.9	-	1.9	ns	
T _{CL}	Minimum pulse width, Low	-	1.9	-	1.9	ns	
Set/Reset	·	1					
T _{RPW}	Minimum pulse width, SR/BY inputs	3.1	-	3.1	-	ns	
T _{RQ}	Delay from SR/BY inputs to XQ/YQ outputs (asynchronous)	-	1.1	-	1.3	ns	
T _{IOGSRQ}	Delay from GSR to XQ/YQ outputs	-	9.9	-	11.7	ns	
F _{TOG}	Toggle frequency (for export control)	-	263	-	263	MHz	

Notes:

1. A zero hold time listing indicates no hold time or a negative hold time.

Block RAM Switching Characteristics

		Speed Grade				
		-6		-5		
Symbol	Description	Min	Max	Min	Max	Units
Sequential Delays		<u>.</u>	<u>.</u>	<u>.</u>	<u>.</u>	<u></u>
Т _{ВСКО}	Clock CLK to DOUT output	-	3.4	-	4.0	ns
Setup/Hold Times	with Respect to Clock CLK ⁽¹⁾					
T _{BACK} / T _{BCKA}	ADDR inputs	1.4 / 0	-	1.4 / 0	-	ns
T _{BDCK} / T _{BCKD}	DIN inputs	1.4 / 0	-	1.4 / 0	-	ns
T _{BECK} / T _{BCKE}	EN inputs	2.9 / 0	-	3.2 / 0	-	ns
T _{BRCK} / T _{BCKR}	RST input	2.7 / 0	-	2.9/0	-	ns
T _{BWCK} / T _{BCKW}	WEN input	2.6 / 0	-	2.8 / 0	-	ns
Clock CLK						
T _{BPWH}	Minimum pulse width, High	-	1.9	-	1.9	ns
T _{BPWL}	Minimum pulse width, Low	-	1.9	-	1.9	ns
T _{BCCS}	CLKA -> CLKB setup time for different ports	-	3.0	-	4.0	ns

Notes:

1. A zero hold time listing indicates no hold time or a negative hold time.

TBUF Switching Characteristics

		Speed	Speed Grade			
		-6	-5	-		
Symbol	Description	Max	Max	Units		
Combinatorial Delay	rs			<u>.</u>		
T _{IO}	IN input to OUT output	0	0	ns		
T _{OFF}	TRI input to OUT output high impedance	0.1	0.2	ns		
T _{ON}	TRI input to valid data on OUT output	0.1	0.2	ns		

JTAG Test Access Port Switching Characteristics

			Speed	l Grade		
		-(6			
Symbol	Description	Min	Max	Min	Max	Units
Setup and Hold Time	s with Respect to TCK					
T _{TAPTCK /} T _{TCKTAP}	TMS and TDI setup and hold times	4.0/2.0	-	4.0/2.0	-	ns
Sequential Delays	-	· · · ·				
T _{TCKTDO}	Output delay from clock TCK to output TDO	-	11.0	-	11.0	ns
FTCK	Maximum TCK clock frequency	-	33	-	33	MHz

Package	Leads	Туре	Maximum I/O	Lead Pitch (mm)	Footprint Area (mm)	Height (mm)	Mass ⁽¹⁾ (g)
VQ100 / VQG100	100	Very Thin Quad Flat Pack (VQFP)	60	0.5	16 x 16	1.20	0.6
TQ144 / TQG144	144	Thin Quad Flat Pack (TQFP)	92	0.5	22 x 22	1.60	1.4
CS144 / CSG144	144	Chip Scale Ball Grid Array (CSBGA)	92	0.8	12 x 12	1.20	0.3
PQ208 / PQG208	208	Plastic Quad Flat Pack (PQFP)	140	0.5	30.6 x 30.6	3.70	5.3
FG256 / FGG256	256	Fine-pitch Ball Grid Array (FBGA)	176	1.0	17 x 17	2.00	0.9
FG456 / FGG456	456	Fine-pitch Ball Grid Array (FBGA)	284	1.0	23 x 23	2.60	2.2

Table 36: Spartan-II Family Package Options

Notes:

1. Package mass is $\pm 10\%$.

Note: Some early versions of Spartan-II devices, including the XC2S15 and XC2S30 ES devices and the XC2S150 with date code 0045 or earlier, included a power-down pin. For more information, see <u>Answer Record 10500</u>.

VCCO Banks

Some of the I/O standards require specific V_{CCO} voltages. These voltages are externally connected to device pins that serve groups of IOBs, called banks. Eight I/O banks result from separating each edge of the FPGA into two banks (see Figure 3 in Module 2). Each bank has multiple V_{CCO} pins which must be connected to the same voltage. In the smaller packages, the V_{CCO} pins are connected between banks, effectively reducing the number of independent banks available (see Table 37). These interconnected banks are shown in the Pinout Tables with V_{CCO} pads for multiple banks connected to the same pin.

Table 37: Independent VCCO Banks Available

Package	VQ100	CS144	FG256
	PQ208	TQ144	FG456
Independent Banks	1	4	8

Package Overview

Table 36 shows the six low-cost, space-saving productionpackage styles for the Spartan-II family.

Each package style is available in an environmentally friendly lead-free (Pb-free) option. The Pb-free packages include an extra 'G' in the package style name. For example, the standard "CS144" package becomes "CSG144" when ordered as the Pb-free option. Leaded (non-Pb-free) packages may be available for selected devices, with the same pin-out and without the "G" in the ordering code; contact Xilinx sales for more information. The mechanical dimensions of the standard and Pb-free packages are similar, as shown in the mechanical drawings provided in Table 38. For additional package information, see <u>UG112</u>: *Device Package User Guide*.

Mechanical Drawings

Detailed mechanical drawings for each package type are available from the Xilinx web site at the specified location in Table 38.

Material Declaration Data Sheets (MDDS) are also available on the <u>Xilinx web site</u> for each package.

Table 38: Xilinx Package Documentation

Package	Drawing	MDDS
VQ100	Package Drawing	PK173_VQ100
VQG100		PK130_VQG100
TQ144	Package Drawing	PK169_TQ144
TQG144		PK126_TQG144
CS144	Package Drawing	PK149_CS144
CSG144		PK103_CSG144
PQ208	Package Drawing	PK166_PQ208
PQG208		PK123_PQG208
FG256	Package Drawing	PK151_FG256
FGG256		PK105_FGG256
FG456	Package Drawing	PK154_FG456
FGG456		PK109_FGG456

Pinout Tables

The following device-specific pinout tables include all packages available for each Spartan[®]-II device. They follow the pad locations around the die, and include Boundary Scan register locations.

XC2S15 Device Pinouts

XC2S15 Pad Name					Bndry
Function	Bank	VQ100	TQ144	CS144	Scan
GND	-	P1	P143	A1	-
TMS	-	P2	P142	B1	-
I/O	7	P3	P141	C2	77
I/O	7	-	P140	C1	80
I/O, V _{REF}	7	P4	P139	D4	83
I/O	7	P5	P137	D2	86
I/O	7	P6	P136	D1	89
GND	-	-	P135	E4	-
I/O	7	P7	P134	E3	92
I/O	7	-	P133	E2	95
I/O, V _{REF}	7	P8	P132	E1	98
I/O	7	P9	P131	F4	101
I/O	7	-	P130	F3	104
I/O, IRDY ⁽¹⁾	7	P10	P129	F2	107
GND	-	P11	P128	F1	-
V _{CCO}	7	P12	P127	G2	-
V _{CCO}	6	P12	P127	G2	-
I/O, TRDY ⁽¹⁾	6	P13	P126	G1	110
V _{CCINT}	-	P14	P125	G3	-
I/O	6	-	P124	G4	113
I/O	6	P15	P123	H1	116
I/O, V _{REF}	6	P16	P122	H2	119
I/O	6	-	P121	H3	122
I/O	6	P17	P120	H4	125
GND	-	-	P119	J1	-
I/O	6	P18	P118	J2	128
I/O	6	P19	P117	J3	131
I/O, V _{REF}	6	P20	P115	K1	134
I/O	6	-	P114	K2	137
I/O	6	P21	P113	K3	140
I/O	6	P22	P112	L1	143
M1	-	P23	P111	L2	146
GND	-	P24	P110	L3	-
M0	-	P25	P109	M1	147
V _{CCO}	6	P26	P108	M2	-
V _{CCO}	5	P26	P107	N1	-

XC2S15 Device Pinouts (Continued)

XC2S15 Pad				Bndry	
Function	Bank	VQ100	TQ144	CS144	Scan
M2	-	P27	P106	N2	148
I/O	5	-	P103	K4	155
I/O, V _{REF}	5	P30	P102	L4	158
I/O	5	P31	P100	N4	161
I/O	5	P32	P99	K5	164
GND	-	-	P98	L5	-
V _{CCINT}	-	P33	P97	M5	-
I/O	5	-	P96	N5	167
I/O	5	-	P95	K6	170
I/O, V _{REF}	5	P34	P94	L6	173
I/O	5	-	P93	M6	176
V _{CCINT}	-	P35	P92	N6	-
I, GCK1	5	P36	P91	M7	185
V _{CCO}	5	P37	P90	N7	-
V _{CCO}	4	P37	P90	N7	-
GND	-	P38	P89	L7	-
I, GCK0	4	P39	P88	K7	186
I/O	4	P40	P87	N8	190
I/O	4	-	P86	M8	193
I/O, V _{REF}	4	P41	P85	L8	196
I/O	4	-	P84	K8	199
I/O	4	-	P83	N9	202
V _{CCINT}	-	P42	P82	M9	-
GND	-	-	P81	L9	-
I/O	4	P43	P80	K9	205
I/O	4	P44	P79	N10	208
I/O, V _{REF}	4	P45	P77	L10	211
I/O	4	-	P76	N11	214
I/O	4	P46	P75	M11	217
I/O	4	P47	P74	L11	220
GND	-	P48	P73	N12	-
DONE	3	P49	P72	M12	223
V _{CCO}	4	P50	P71	N13	-
V _{CCO}	3	P50	P70	M13	-
PROGRAM	-	P51	P69	L12	226
I/O (INIT)	3	P52	P68	L13	227
I/O (D7)	3	P53	P67	K10	230
I/O	3	-	P66	K11	233
I/O, V _{REF}	3	P54	P65	K12	236
I/O	3	P55	P63	J10	239
I/O (D6)	3	P56	P62	J11	242

Bndry

Scan

203

206

209

212

215

218

-

219

-

-

220

227

230

233

236

239

242

-

-

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245

248

251

254

257

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260

263

266

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275

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-

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276

280

283

286

289

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292

XC2S30 Device Pinouts

XC2S30 Pad	Name				Dada			Dodov] [XC2S30 Pad Name					
Function	Bank	VQ100	TQ144	CS144	PQ208	Scan		Function	Bank	VQ100	TQ144	CS144	PQ208		
GND	-	P1	P143	A1	P1	-		I/O, V _{REF}	6	P20	P115	K1	P45		
TMS	-	P2	P142	B1	P2	-		I/O	6	-	-	-	P46		
I/O	7	P3	P141	C2	P3	113	1	I/O	6	-	P114	K2	P47		
I/O	7	-	P140	C1	P4	116	1	I/O	6	P21	P113	K3	P48		
I/O	7	-	-	-	P5	119	1	I/O	6	P22	P112	L1	P49		
I/O, V _{REF}	7	P4	P139	D4	P6	122		M1	-	P23	P111	L2	P50		
I/O	7	-	P138	D3	P8	125		GND	-	P24	P110	L3	P51		
I/O	7	P5	P137	D2	P9	128	1	MO	-	P25	P109	M1	P52		
I/O	7	P6	P136	D1	P10	131	1	V _{CCO}	6	P26	P108	M2	P53		
GND	-	-	P135	E4	P11	-	1	V _{CCO}	5	P26	P107	N1	P53		
V _{cco}	7	-	-	-	P12	-	1	M2	-	P27	P106	N2	P54		
I/O	7	P7	P134	E3	P14	134	1	I/O	5	-	P103	K4	P57		
I/O	7	-	P133	E2	P15	137	1	I/O	5	-	-	-	P58		
I/O	7	-	-	-	P16	140		I/O, V _{REF}	5	P30	P102	L4	P59		
I/O	7	-	-	-	P17	143		I/O	5	-	P101	M4	P61		
I/O	7	-	-	-	P18	146	1	I/O	5	P31	P100	N4	P62		
GND	-	-	-	-	P19	-		I/O	5	P32	P99	K5	P63		
I/O, V _{REF}	7	P8	P132	E1	P20	149	1	GND	-	-	P98	L5	P64		
I/O	7	P9	P131	F4	P21	152		V _{CCO}	5	-	-	-	P65		
I/O	7	-	P130	F3	P22	155	1	V _{CCINT}	-	P33	P97	M5	P66		
I/O	7	-	-	-	P23	158	1	I/O	5	-	P96	N5	P67		
I/O, IRDY ⁽¹⁾	7	P10	P129	F2	P24	161	1	I/O	5	-	P95	K6	P68		
GND	-	P11	P128	F1	P25	-		I/O	5	-	-	-	P69		
V _{CCO}	7	P12	P127	G2	P26	-	1	I/O	5	-	-	-	P70		
V _{cco}	6	P12	P127	G2	P26	-		I/O	5	-	-	-	P71		
I/O, TRDY ⁽¹⁾	6	P13	P126	G1	P27	164	1	GND	-	-	-	-	P72		
V _{CCINT}	-	P14	P125	G3	P28	-	1	I/O, V _{REF}	5	P34	P94	L6	P73		
I/O	6	-	P124	G4	P29	170	1	I/O	5	-	-	-	P74		
I/O	6	P15	P123	H1	P30	173	1	I/O	5	-	P93	M6	P75		
I/O, V _{REF}	6	P16	P122	H2	P31	176		V _{CCINT}	-	P35	P92	N6	P76		
GND	-	-	-	-	P32	-		I, GCK1	5	P36	P91	M7	P77		
I/O	6	-	-	-	P33	179	1	V _{CCO}	5	P37	P90	N7	P78		
I/O	6	-	-	-	P34	182		V _{CCO}	4	P37	P90	N7	P78		
I/O	6	-	-	-	P35	185	1	GND	-	P38	P89	L7	P79		
I/O	6	-	P121	H3	P36	188	1	I, GCK0	4	P39	P88	K7	P80		
I/O	6	P17	P120	H4	P37	191		I/O	4	P40	P87	N8	P81		
V _{CCO}	6	-	-	-	P39	-	1 [I/O	4	-	P86	M8	P82		
GND	-	-	P119	J1	P40	-	1 [I/O	4	-	-	-	P83		
I/O	6	P18	P118	J2	P41	194	1 [I/O, V _{REF}	4	P41	P85	L8	P84		
I/O	6	P19	P117	J3	P42	197	1 [GND	-	-	-	-	P85		
I/O	6	-	P116	J4	P43	200] [I/O	4	-	-	-	P86		

XC2S50 Device Pinouts (Continued)

XC2S50 Pad Name					Bndry
Function	Bank	TQ144	PQ208	FG256	Scan
I/O	3	-	-	J14	503
I/O	3	P56	P127	K15	506
V _{CCINT}	-	P55	P128	V _{CCINT} *	-
I/O, TRDY ⁽¹⁾	3	P54	P129	J15	512
V _{CCO}	3	P53	P130	V _{CCO} Bank 3*	-
V _{CCO}	2	P53	P130	V _{CCO} Bank 2*	-
GND	-	P52	P131	GND*	-
I/O, IRDY ⁽¹⁾	2	P51	P132	H16	515
I/O	2	-	P133	H14	518
I/O	2	P50	P134	H15	521
I/O	2	-	-	J13	524
I/O (D3)	2	P49	P135	G16	527
I/O, V _{REF}	2	P48	P136	H13	530
GND	-	-	P137	GND*	-
I/O	2	-	P138	G14	533
I/O	2	-	P139	G15	536
I/O	2	-	P140	G12	539
I/O	2	-	-	F16	542
I/O	2	P47	P141	G13	545
I/O (D2)	2	P46	P142	F15	548
V _{CCINT}	-	-	P143	V _{CCINT} *	-
V _{CCO}	2	-	P144	V _{CCO} Bank 2*	-
GND	-	P45	P145	GND*	-
I/O (D1)	2	P44	P146	E16	551
I/O	2	P43	P147	F14	554
I/O	2	P42	P148	D16	557
I/O	2	-	-	F12	560
I/O	2	-	P149	E15	563
I/O, V _{REF}	2	P41	P150	F13	566
GND	-	-	-	GND*	-
I/O	2	-	P151	E14	569
I/O	2	-	-	C16	572
I/O	2	P40	P152	E13	575
I/O	2	-	-	B16	578
I/O (DIN, D0)	2	P39	P153	D14	581
I/O (DOUT, BUSY)	2	P38	P154	C15	584
CCLK	2	P37	P155	D15	587
V _{CCO}	2	P36	P156	V _{CCO} Bank 2*	-

XC2S50 Device Pinouts (Continued)

XC2S50 Pad Name					Bndry
Function	Bank	TQ144	PQ208	FG256	Scan
V _{CCO}	1	P35	P156	V _{CCO} Bank 1*	-
TDO	2	P34	P157	B14	-
GND	-	P33	P158	GND*	-
TDI	-	P32	P159	A15	-
I/O (CS)	1	P31	P160	B13	0
I/O (WRITE)	1	P30	P161	C13	3
I/O	1	-	-	C12	6
I/O	1	P29	P162	A14	9
I/O	1	-	-	D12	12
I/O	1	-	P163	B12	15
GND	-	-	-	GND*	-
I/O, V _{REF}	1	P28	P164	C11	18
I/O	1	-	P165	A13	21
I/O	1	-	-	D11	24
I/O	1	-	P166	A12	27
I/O	1	P27	P167	E11	30
I/O	1	P26	P168	B11	33
GND	-	P25	P169	GND*	-
V _{CCO}	1	-	P170	V _{CCO} Bank 1*	-
V _{CCINT}	-	P24	P171	V _{CCINT} *	-
I/O	1	P23	P172	A11	36
I/O	1	P22	P173	C10	39
I/O	1	-	P174	B10	45
I/O	1	-	P175	D10	48
I/O	1	-	P176	A10	51
GND	-	-	P177	GND*	-
I/O, V _{REF}	1	P21	P178	B9	54
I/O	1	-	P179	E10	57
I/O	1	-	-	A9	60
I/O	1	P20	P180	D9	63
I/O	1	P19	P181	A8	66
I, GCK2	1	P18	P182	C9	72
GND	-	P17	P183	GND*	-
V _{CCO}	1	P16	P184	V _{CCO} Bank 1*	-
V _{cco}	0	P16	P184	V _{CCO} Bank 0*	-
I, GCK3	0	P15	P185	B8	73
V _{CCINT}	-	P14	P186	V_{CCINT}^{*}	-
I/O	0	P13	P187	A7	80

XC2S150 Device Pinouts

XC2S150 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
GND	-	P1	GND*	GND*	-
TMS	-	P2	D3	D3	-
I/O	7	P3	C2	B1	221
I/O	7	-	-	E4	224
I/O	7	-	-	C1	227
I/O	7	-	A2	F5	230
GND	-	-	GND*	GND*	-
I/O	7	P4	B1	D2	233
I/O	7	-	-	E3	236
I/O	7	-	-	F4	239
I/O	7	-	E3	G5	242
I/O	7	P5	D2	F3	245
GND	-	-	GND*	GND*	-
V _{CCO}	7	-	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
I/O, V _{REF}	7	P6	C1	E2	248
I/O	7	P7	F3	E1	251
I/O	7	-	-	G4	254
I/O	7	-	-	G3	257
I/O	7	-	E2	H5	260
I/O	7	P8	E4	F2	263
I/O	7	-	-	F1	266
I/O, V _{REF}	7	P9	D1	H4	269
I/O	7	P10	E1	G1	272
GND	-	P11	GND*	GND*	-
V _{CCO}	7	P12	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
V _{CCINT}	-	P13	V _{CCINT} *	V _{CCINT} *	-
I/O	7	P14	F2	H3	275
I/O	7	P15	G3	H2	278
I/O	7	-	-	H1	284
I/O	7	-	F1	J5	287
I/O	7	P16	F4	J2	290
I/O	7	-	-	J3	293
I/O	7	P17	F5	K5	299
I/O	7	P18	G2	K1	302
GND	-	P19	GND*	GND*	-
V _{CCO}	7	-	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
I/O, V _{REF}	7	P20	H3	K3	305
I/O	7	P21	G4	K4	308
I/O	7	-	H2	L6	311

XC2S150 Device Pinouts (Continued)

XC2S150 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
I/O	7	P22	G5	L1	314
I/O	7	-	-	L5	317
I/O	7	P23	H4	L4	320
I/O, IRDY ⁽¹⁾	7	P24	G1	L3	323
GND	-	P25	GND*	GND*	-
V _{CCO}	7	P26	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
V _{CCO}	6	P26	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
I/O, TRDY ⁽¹⁾	6	P27	J2	M1	326
V _{CCINT}	-	P28	V_{CCINT}^{*}	V_{CCINT}^{*}	-
I/O	6	-	-	M6	332
I/O	6	P29	H1	M3	335
I/O	6	-	J4	M4	338
I/O	6	P30	J1	M5	341
I/O, V _{REF}	6	P31	J3	N2	344
V _{CCO}	6	-	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	P32	GND*	GND*	-
I/O	6	P33	K5	N3	347
I/O	6	P34	K2	N4	350
I/O	6	-	-	N5	356
I/O	6	P35	K1	P2	359
I/O	6	-	K3	P4	362
I/O	6	-	-	R1	365
I/O	6	P36	L1	P3	371
I/O	6	P37	L2	R2	374
V _{CCINT}	-	P38	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	6	P39	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	P40	GND*	GND*	-
I/O	6	P41	K4	T1	377
I/O, V _{REF}	6	P42	M1	R4	380
I/O	6	-	-	T2	383
I/O	6	P43	L4	U1	386
I/O	6	-	M2	R5	389
I/O	6	-	-	V1	392
I/O	6	-	-	T5	395
I/O	6	P44	L3	U2	398
I/O, V _{REF}	6	P45	N1	Т3	401
V _{CCO}	6	-	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	-	GND*	GND*	-

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
I/O	6	-	-	T2	449
I/O	6	P43	L4	U1	452
GND	-	-	GND*	GND*	-
I/O	6	-	M2	R5	455
I/O	6	-	-	V1	458
I/O	6	-	-	T5	461
I/O	6	P44	L3	U2	464
I/O, V _{REF}	6	P45	N1	Т3	467
V _{CCO}	6	-	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	-	GND*	GND*	-
I/O	6	P46	P1	T4	470
I/O	6	-	L5	W1	473
GND	-	-	GND*	GND*	-
I/O	6	-	-	V2	476
I/O	6	-	-	U4	482
I/O, V _{REF}	6	P47	N2	Y1	485
GND	-	-	GND*	GND*	-
I/O	6	-	M4	W2	488
I/O	6	-	-	V3	491
I/O	6	-	-	V4	494
I/O	6	P48	R1	Y2	500
I/O	6	P49	M3	W3	503
M1	-	P50	P2	U5	506
GND	-	P51	GND*	GND*	-
MO	-	P52	N3	AB2	507
V _{CCO}	6	P53	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
V _{CCO}	5	P53	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
M2	-	P54	R3	Y4	508
I/O	5	-	-	W5	518
I/O	5	-	-	AB3	521
I/O	5	-	N5	V7	524
GND	-	-	GND*	GND*	-
I/O, V _{REF}	5	P57	T2	Y6	527
I/O	5	-	-	AA4	530
I/O	5	-	-	AB4	536
I/O	5	-	P5	W6	539
I/O	5	P58	Т3	Y7	542
GND	-	-	GND*	GND*	-

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
V _{CCO}	5	-	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
I/O, V _{REF}	5	P59	T4	AA5	545
I/O	5	P60	M6	AB5	548
I/O	5	-	-	V8	551
I/O	5	-	-	AA6	554
I/O	5	-	T5	AB6	557
GND	-	-	GND*	GND*	-
I/O	5	P61	N6	AA7	560
I/O	5	-	-	W7	563
I/O, V _{REF}	5	P62	R5	W8	569
I/O	5	P63	P6	Y8	572
GND	-	P64	GND*	GND*	-
V _{CCO}	5	P65	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
V _{CCINT}	-	P66	V _{CCINT} *	V _{CCINT} *	-
I/O	5	P67	R6	AA8	575
I/O	5	P68	M7	V9	578
I/O	5	-	-	AB8	581
I/O	5	-	-	W9	584
I/O	5	-	-	AB9	587
GND	-	-	GND*	GND*	-
I/O	5	P69	N7	Y9	590
I/O	5	-	-	V10	593
I/O	5	-	-	AA9	596
I/O	5	P70	Т6	W10	599
I/O	5	P71	P7	AB10	602
GND	-	P72	GND*	GND*	-
V _{CCO}	5	-	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
I/O, V _{REF}	5	P73	P8	Y10	605
I/O	5	P74	R7	V11	608
I/O	5	-	-	AA10	614
I/O	5	-	T7	W11	617
I/O	5	P75	Т8	AB11	620
I/O	5	-	-	U11	623
V _{CCINT}	-	P76	V _{CCINT} *	V _{CCINT} *	-
I, GCK1	5	P77	R8	Y11	635
V _{CCO}	5	P78	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
V _{CCO}	4	P78	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	P79	GND*	GND*	-

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
V _{CCO}	3	P117	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
V _{CCINT}	-	P118	V _{CCINT} *	V _{CCINT} *	-
I/O (D5)	3	P119	M16	R21	833
I/O	3	P120	K14	P18	836
I/O	3	-	-	R22	839
I/O	3	-	-	P19	842
I/O	3	-	L16	P20	845
GND	-	-	GND*	GND*	-
I/O	3	P121	K13	P21	848
I/O	3	-	-	N19	851
I/O	3	-	-	P22	854
I/O	3	P122	L15	N18	857
I/O	3	P123	K12	N20	860
GND	-	P124	GND*	GND*	-
V _{CCO}	3	-	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
I/O, V _{REF}	3	P125	K16	N21	863
I/O (D4)	3	P126	J16	N22	866
I/O	3	-	-	M17	872
I/O	3	-	J14	M19	875
I/O	3	P127	K15	M20	878
I/O	3	-	-	M18	881
V _{CCINT}	-	P128	V _{CCINT} *	V _{CCINT} *	-
I/O, TRDY ⁽¹⁾	3	P129	J15	M22	890
V _{CCO}	3	P130	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
V _{CCO}	2	P130	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P131	GND*	GND*	-
I/O, IRDY ⁽¹⁾	2	P132	H16	L20	893
I/O	2	P133	H14	L17	896
I/O	2	-	-	L18	902
I/O	2	P134	H15	L21	905
I/O	2	-	J13	L22	908
I/O	2	-	-	K19	911
I/O (D3)	2	P135	G16	K20	917
I/O, V _{REF}	2	P136	H13	K21	920
V _{CCO}	2	-	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P137	GND*	GND*	-
I/O	2	P138	G14	K22	923
I/O	2	P139	G15	J21	926

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name					Bndrv
Function	Bank	PQ208	FG256	FG456	Scan
I/O	2	-	-	K18	929
I/O	2	-	-	J20	932
I/O	2	P140	G12	J18	935
GND	-	-	GND*	GND*	-
I/O	2	-	F16	J22	938
I/O	2	-	-	J19	941
I/O	2	-	-	H21	944
I/O	2	P141	G13	H19	947
I/O (D2)	2	P142	F15	H20	950
V _{CCINT}	-	P143	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	2	P144	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P145	GND*	GND*	-
I/O (D1)	2	P146	E16	H22	953
I/O, V _{REF}	2	P147	F14	H18	956
I/O	2	-	-	G21	962
I/O	2	P148	D16	G18	965
GND	-	-	GND*	GND*	-
I/O	2	-	F12	G20	968
I/O	2	-	-	G19	971
I/O	2	-	-	F22	974
I/O	2	P149	E15	F19	977
I/O, V _{REF}	2	P150	F13	F21	980
V _{CCO}	2	-	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	-	GND*	GND*	-
I/O	2	P151	E14	F20	983
I/O	2	-	C16	F18	986
GND	-	-	GND*	GND*	-
I/O	2	-	-	E22	989
I/O	2	-	-	E21	995
I/O, V _{REF}	2	P152	E13	D22	998
GND	-	-	GND*	GND*	-
I/O	2	-	B16	E20	1001
I/O	2	-	-	D21	1004
I/O	2	-	-	C22	1007
I/O (DIN, D0)	2	P153	D14	D20	1013
I/O (DOUT, BUSY)	2	P154	C15	C21	1016
CCLK	2	P155	D15	B22	1019
V _{CCO}	2	P156	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-